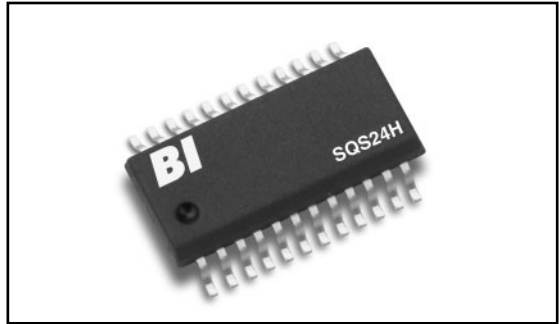


NICHROME ON SILICON

HSTL Termination Circuit

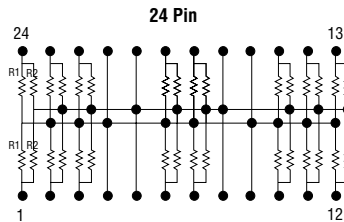
Thin Film Resistor Networks

NEW PRODUCT



SCHEMATIC

HSTL (High Speed Transceiver Logic)
Termination Network



4

ELECTRICAL

Standard Resistance Range, Ohms	75 to 200
Operating Temperature Range	-55°C to +125°C
Interlead Capacitance	<2pF
Insulation Resistance	≥10,000 Megohms
Noise, Maximum (MIL-STD-202, Method 308)	-25dB
Maximum Operating Voltage	100Vdc or √PR

ENVIRONMENTAL

Thermal Shock plus Power Conditioning	ΔR 0.1%
Moisture Resistance	ΔR 0.1%
Mechanical Shock	ΔR 0.1%
High Temperature Exposure, Maximum	ΔR 0.1%
Marking Permanency	per MIL-STD-202, Method 215
Flammability	UL-94V-0 Rated
Storage Temperature Range	-55°C to +125°C

Specifications subject to change without notice.

MECHANICAL

Lead Plating	80/20 Tin Lead
Lead Material	Copper Alloy
Lead Configuration	Gull Wing
Lead Coplanarity	0.004" (0.102mm)
Substrate Material	Silicon
Resistor Material	Passivated Nichrome
Body Material	Molded Epoxy

TOLERANCES

Accuracy Code	F	G	J
Absolute Resistance Tolerances at 25°C	1.0%	2.0%	5.0%
Ratio Tolerances at 25°C	1.0%	N/A	N/A
Temperature Coefficient of Resistance (TCR Code)			±100ppm/°C (S)
Temperature Coefficient of Resistance, Tracking			±5ppm/°C

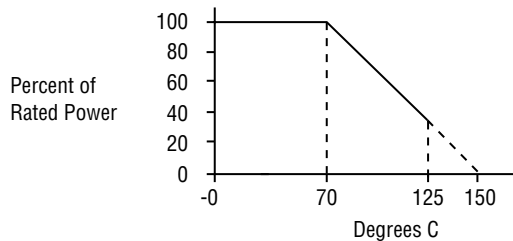
PACKAGE POWER, WATTS @ 70°C, MAX.

QSOP 24

1.0

Power per resistor @ 70°C, Max. is 100mW, not to exceed package power.

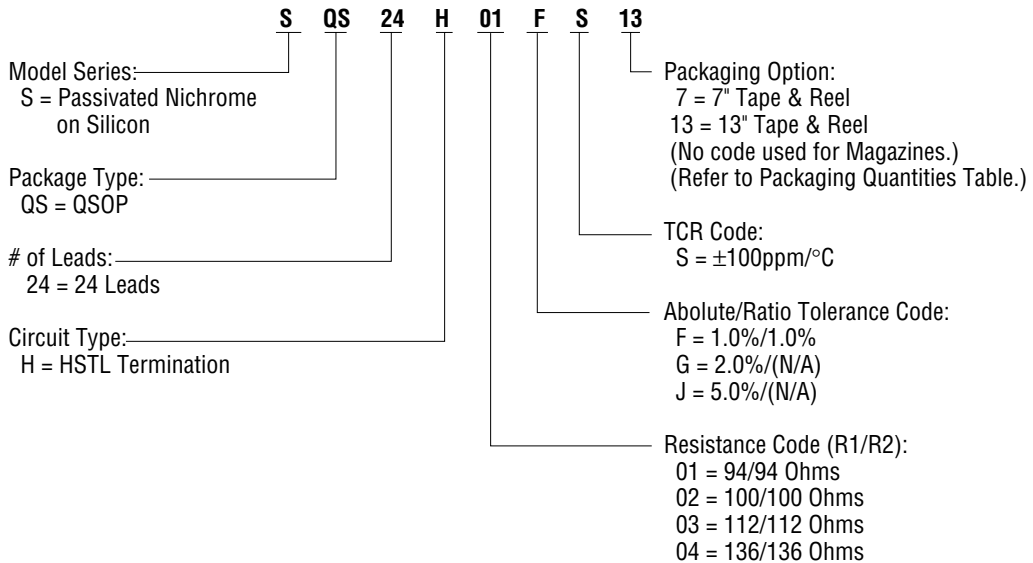
POWER DERATING CURVE



OUTLINE DIMENSIONS

Refer to standard package Outline Dimensions at the end of the Model NiCr on Si section.

ORDERING INFORMATION



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CUSTOM SOLUTIONS

Networks designed to meet your specific electrical and packaging requirements are available. Please contact the factory for technical assistance, price and availability.